1N91x, 1N4x48, FDLL914, FDLL4x48

Small Signal Diode



ON Semiconductor®

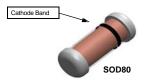
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ORDERING INFORMATION

| Part Number | Marking | Package | Packing Method |
|---------------|---------|------------------|----------------|
| 1N914 | 914 | DO-204AH (DO-35) | Bulk |
| 1N914-T50A | 914 | DO-204AH (DO-35) | Ammo |
| 1N914TR | 914 | DO-204AH (DO-35) | Tape and Reel |
| 1N914ATR | 914A | DO-204AH (DO-35) | Tape and Reel |
| 1N914B | 914B | DO-204AH (DO-35) | Bulk |
| 1N914BTR | 914B | DO-204AH (DO-35) | Tape and Reel |
| 1N916 | 916 | DO-204AH (DO-35) | Bulk |
| 1N916A | 916A | DO-204AH (DO-35) | Bulk |
| 1N916B | 916B | DO-204AH (DO-35) | Bulk |
| 1N4148 | 4148 | DO-204AH (DO-35) | Bulk |
| 1N4148TA | 4148 | DO-204AH (DO-35) | Ammo |
| 1N4148-T26A | 4148 | DO-204AH (DO-35) | Ammo |
| 1N4148-T50A | 4148 | DO-204AH (DO-35) | Ammo |
| 1N4148TR | 4148 | DO-204AH (DO-35) | Tape and Reel |
| 1N4148-T50R | 4148 | DO-204AH (DO-35) | Tape and Reel |
| 1N4448 | 4448 | DO-204AH (DO-35) | Bulk |
| 1N4448TR | 4448 | DO-204AH (DO-35) | Tape and Reel |
| FDLL914 | Black | SOD-80 | Tape and Reel |
| FDLL914A | Black | SOD-80 | Tape and Reel |
| FDLL914B | Black | SOD-80 | Tape and Reel |
| FDLL4148 | Black | SOD-80 | Tape and Reel |
| FDLL4148-D87Z | Black | SOD-80 | Tape and Reel |
| FDLL4448 | Black | SOD-80 | Tape and Reel |
| FDLL4448-D87Z | Black | SOD-80 | Tape and Reel |



DO-35 Cathode is denoted with a black band



THE PLACEMENT OF THE EXPANSION GAP HAS NO RELATIONSHIP TO THE LOCATION OF THE CATHODE TERMINAL

SOD-80 COLOR BAND MARKING

DEVICE 1ST BAND FDLL914 FDLL914A FDLL914B FDLL4148 FDLL4448 BLACK BLACK BLACK BLACK BLACK

-1st band denotes cathode terminal

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ABSOLUTE MAXIMUM RATINGS (Values are at T_A = 25°C unless otherwise noted) (Note 1)

| Rating | Symbol | Value | Unit |
|---|------------------|-------------|------|
| Maximum Repetitive Reverse Voltage | V_{RRM} | 100 | V |
| Average Rectified Forward Current | I _O | 200 | mA |
| DC Forward Current | I _F | 300 | mA |
| Recurrent Peak Forward Current | I _f | 400 | mA |
| Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 s | I _{FSM} | 1.0 | Α |
| Pulse Width = 1.0 μs | | 4.0 | Α |
| Storage Temperature Range | T _{STG} | -65 to +200 | °C |
| Operating Junction Temperature Range | TJ | -55 to +175 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Parameter | Symbol | Max | Unit |
|---|----------------|-----|------|
| Power Dissipation | P_{D} | 500 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{	heta JA}$ | 300 | °C |

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25$ °C unless otherwise noted) (Note 2)

| Symbol | Pai | rameter | Conditions | Min | Max | Unit |
|-----------------|-------------------|--------------------|--|------|-------|------|
| V_{R} | Breakdown Voltage | | I _R = 100 μA | 100 | | V |
| | | | I _R = 5.0 μA | 75 | | V |
| V _F | Forward Voltage | 914B / 4448 | I _F = 5.0 mA | 0.62 | 0.72 | V |
| | | 916B | I _F = 5.0 mA | 0.63 | 0.73 | V |
| | | 914 / 916 / 4148 | I _F = 10 mA | | 1.0 | V |
| | | 914A / 916A | I _F = 20 mA | | 1.0 | V |
| | | 916B | I _F = 20 mA | | 1.0 | V |
| | | 914B / 4448 | I _F = 100 mA | | 1.0 | V |
| I _R | Reverse Leakage | | V _R = 20 V | | 0.025 | μΑ |
| | | | V _R = 20 V, T _A = 150°C | | 50 | μΑ |
| | | | V _R = 75 V | | 5.0 | μΑ |
| C _T | Total Capacitance | 916/916A/916B/4448 | V _R = 0, f = 1.0 MHz | | 2.0 | pF |
| | | 914/914A/914B/4148 | V _R = 0, f = 1.0 MHz | | 4.0 | pF |
| t _{rr} | Reverse Recovery | - Fime | $I_F = 10 \text{ mA}, V_R = 6.0 \text{ V (600 mA)}$ $I_{rr} = 1.0 \text{ mA}, R_L = 100 \Omega$ | | 4.0 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Non-recurrent square wave $P_W = 8.3$ ms.

^{1.} These ratings are limiting values above which the serviceability of the diode may be impaired.

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TYPICAL PERFORMANCE CHARACTERISTICS

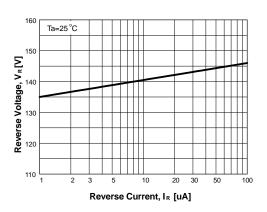


Figure 1. Reverse Voltage vs. Reverse Current B_V – 1.0 to 100 μA

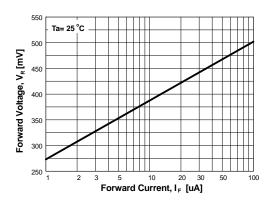


Figure 3. Forward Voltage vs. Forward Current V_F – 1 to 100 μA

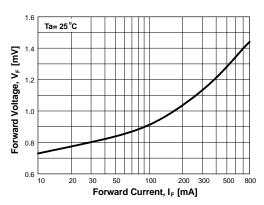
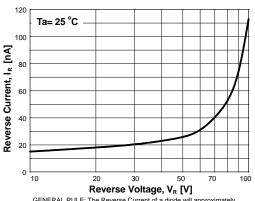


Figure 5. Forward Voltage vs. Forward Current $V_F - 10$ to 800 mA



GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

Figure 2. Reverse Current vs. Reverse Voltage I_R – 10 to 100 V

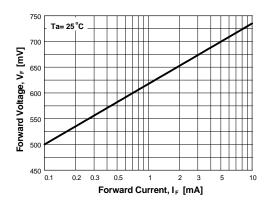


Figure 4. Forward Voltage vs. Forward Current V_F – 0.1 to 10 mA

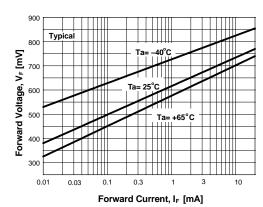


Figure 6. Forward Voltage vs. Ambient Temperature V_F - 0.01 - 20 mA (- 40 to +65°C)

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TYPICAL PERFORMANCE CHARACTERISTICS

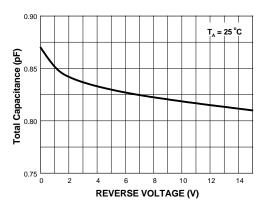


Figure 7. Total Capacitance

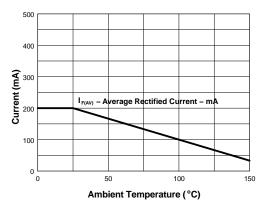


Figure 9. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (I_A)

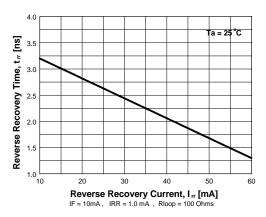


Figure 8. Reverse Recovery Time vs. Reverse Recovery Current

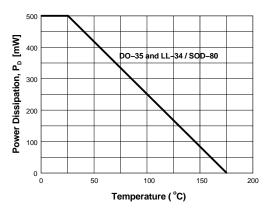
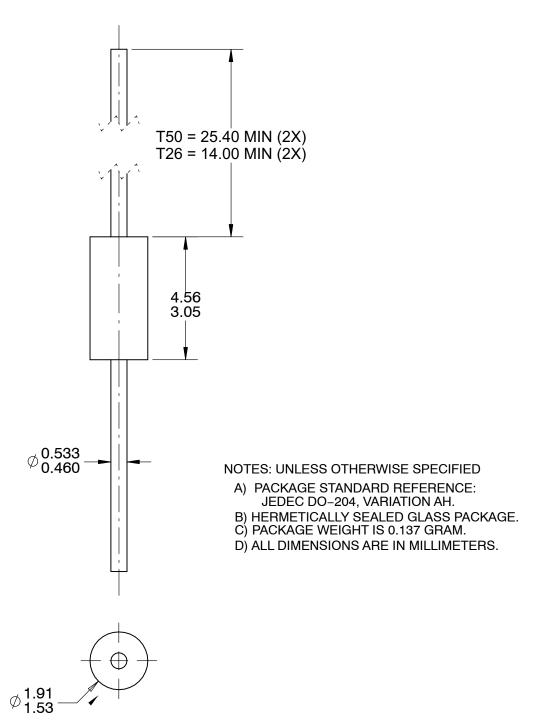


Figure 10. Power Derating Curve



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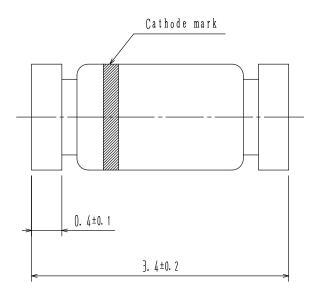
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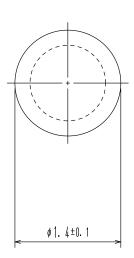
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